TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCXH16652FT

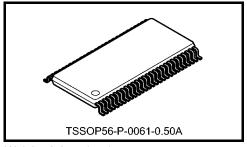
Low-Voltage 16-Bit Bus Transceiver/Register with Bushold

The TC74VCXH16652FT is a high-performance CMOS 16-bit bus transceiver/register. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is bus transceiver with 3-state outputs, D-type flip-flops, and control circuitry arranged for multiplexed transmission of data directly from the internal registers.

The A, B data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25 g (typ.)

Features (Note)

- Low-voltage operation: V_{CC} = 1.8 to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation : $t_{pd} = 2.9 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V})$

 $t_{pd} = 3.5 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V)}$

 $: t_{pd} = 7.0 \text{ ns (max) (V}_{CC} = 1.8 \text{ V})$

- 3.6-V tolerant control inputs
- Output current: $I_{OH}/I_{OL} = \pm 24 \text{ mA (min) (V}_{CC} = 3.0 \text{ V)}$

 $: I_{OH}/I_{OL} = \pm 18 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$

 $: I_{OH}/I_{OL} = \pm 6 \text{ mA (min) (V}_{CC} = 1.8 \text{ V)}$

- Latch-up performance: -300 mA
- ESD performance: Machine model $\geq \pm 200 \text{ V}$

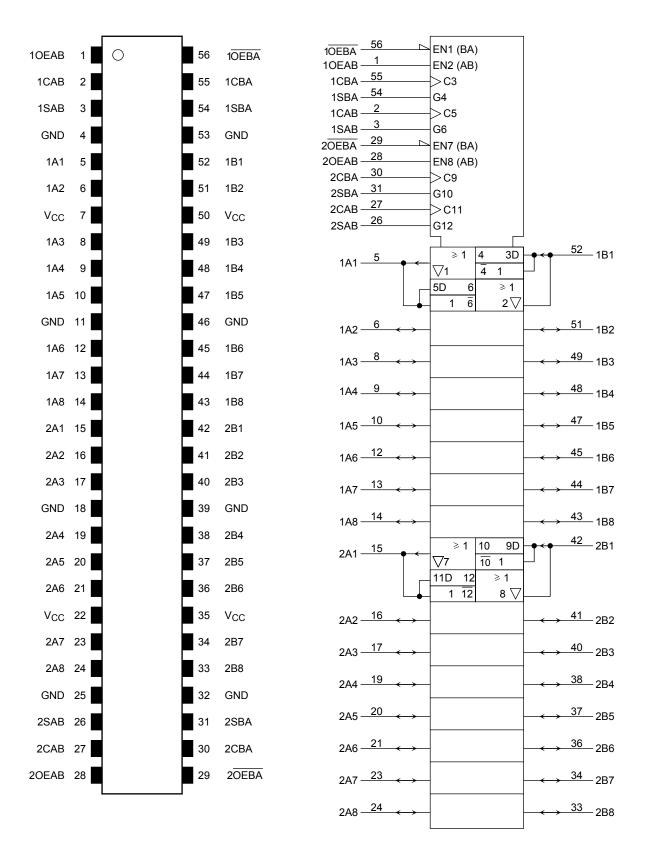
Human body model ≥ ±2000 V

• Package: TSSOP

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

Pin Assignment (top view)

IEC Logic Symbol





Truth Table

		Contro	I Inputs			В	us	- Function					
OEAB	OEBA	CAB	CBA	SAB	SBA	Α	В	Function					
		X*	X*	Х	Х	Input	Input	The output functions of A and B Busses are					
L	Н	^*	^*	^	^	Z	Z	disabled.					
	П	4		X	X	X	X	Both A and B Busses are used as inputs to the internal flip-flops. Data on the Bus will be stored on the rising edge of the Clock.					
						Input	Output						
		X*	X*	L	X	L	L	The data on the A bus are displayed on the B bus.					
						Н	Н						
		$ \uparrow $	X*	L	X	L	L	The data on the A bus are displayed on the B Bus, and are stored into the A storage					
Н	Н		^*	_	^	Н	Н	flip-flops on the rising edge of CAB.					
		X*	X*	Н	х	х	Qn	The data in the A storage flop-flops are displayed on the B Bus.					
	storage flip flops on the	_		The data on the A Bus are stored into the A									
			X*	Н	Х	н	Н	storage flip-flops on the rising edge of CAB, and the stored data propagate directly onto the B Bus.					
						Output	Input						
		X*	X*	X	L	L	L	L	L	L	L	L The data on the B B A bus.	The data on the B Bus are displayed on the A bus.
						Н	Н						
		X*		X	L	L	L	The data on the B Bus are displayed on the A Bus, and are stored into the B storage					
L	L	^.		^	L	Н	Н	flip-flops on the rising edge of CBA.					
		X*	X*	X	Н	Qn	×	The data in the B storage flip-flops are displayed on the A Bus.					
			★			L	L	The data on the B Bus are stored into the B					
		X*		X	Н	н	Н	storage flip-flops on the rising edge of CBA, and the stored data propagate directly onto the A Bus.					
						Output	Output						
н	L	X*	X*	Ι	н	Qn	Qn	The data in the A storage flop-flops are displayed on the B Bus, and the data in the B storage flop-flops are displayed on the A.					

X: Don't care

Z: High impedance

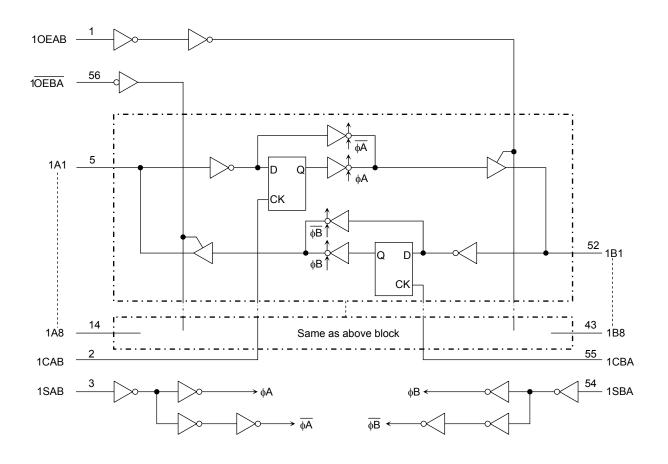
Qn: The data stored into the internal flip-flops by most recent low to high transition of the clock inputs.

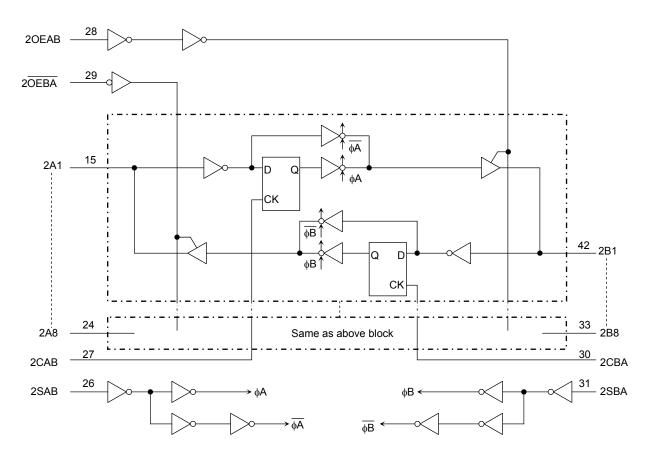
*: The clocks are not internally gated with either OEAB or $\overline{\text{OEBA}}$.

Therefore, data on the A and/or B busses may be clocked into the storage flip-flops at any time.

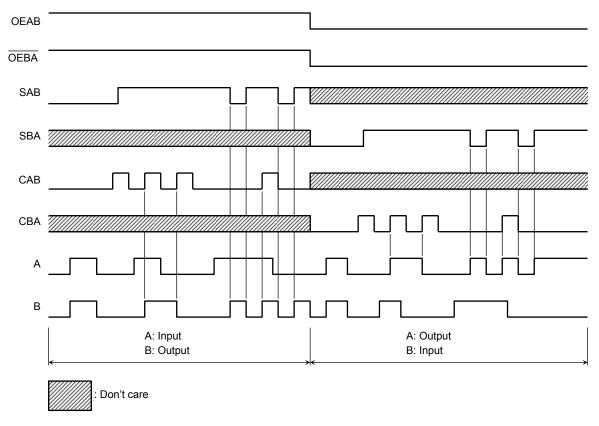
3

System Diagram





Timing Chart



Absolute Maximum Ratings (Note 1)

Characteristics		Symbol	Rating	Unit	
Power sup	oply voltage	V_{CC}	-0.5 to 4.6	V	
DC input	(OEAB, OEBA, SAB, SBA, CAB, CBA)		-0.5 to 4.6	.,	
voltage	(An, Bn)	V_{IN}	-0.5 to V _{CC} + 0.5	V	
	(AII, DII)		(Note 2)		
DC	(* 5	V _{OUT}	-0.5 to V _{CC} + 0.5	,,	
output voltage	output (An, Bn) voltage		(Note 3)	V	
Input diod	e current	lıK	-50	mA	
Output dic	ode current	lok	±50 (Note 4)	mA	
Output current		lout	±50	mA	
Power dissipation		P _D	400	mW	
DC V _{CC} /ground current per supply pin		I _{CC} /I _{GND}	±100	mA	
Storage te	emperature	T _{stg}	-65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

5

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$



Operating Ranges (Note 1) (Note 2)

Characteristics		Symbol	Rating	Unit
		Vaa	1.8 to 3.6	V
rower sup	oply voltage	V _{CC}	1.2 to 3.6 (Note 3)	V
Input	(OEAB, OEBA, SAB, SBA, CAB, CBA)	VIN	-0.3 to 3.6	V
voltage	(An, Bn)		0 to V _{CC} (Note 4)	
Output voltage	(An, Bn)	V _{OUT}	0 to V _{CC} (Note 5)	V
			±24 (Note 6)	
Output cu	Output current		±18 (Note 7)	mA
			±6 (Note 8)	
Operating temperature		T _{opr}	-40 to 85	°C
Input rise	and fall time	dt/dv	0 to 10 (Note 9)	ns/V

- Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

 Unused inputs must be tied to either VCC or GND.
- Note 2: Floating or unused control inputs must be held high or low.
- Note 3: Data retention only
- Note 4: OFF state
- Note 5: High or low state
- Note 6: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
- Note 7: $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
- Note 8: $V_{CC} = 1.8 \text{ V}$
- Note 9: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

6



Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C, 2.7 V < V_{CC} \leq 3.6 V)

Characteristics		Symbol	Test Condition			Min	Max	Unit
		-			V _{CC} (V)			
Input voltage	H-level	V _{IH}	-	_	2.7 to 3.6	2.0	_	V
input voltage	L-level	V _{IL}	-	_	2.7 to 3.6	_	0.8	ľ
				$I_{OH} = -100 \mu A$	2.7 to 3.6	V _{CC} - 0.2	_	
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12 mA	2.7	2.2	_	
				I _{OH} = -18 mA	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V
				$I_{OL} = 100 \mu A$	2.7 to 3.6	_	0.2	
	Llevel		Mar Mar on Mar	I _{OL} = 12 mA	2.7	_	0.4	
	L-level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 18 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage current (OEAB, OEBA), SAB,	SBA, CAB,	I _{IN}	V _{IN} = 0 to 3.6 V		2.7 to 3.6	_	±5.0	μА
Bushold input minimun	n drive hold		V _{IN} = 0.8 V		3.0	75	_	
current		I (HOLD)	V _{IN} = 2.0 V		3.0	-75	_	μΑ
Bushold input over-driv	ve current to			(Note 1)	3.6	_	450	^
change state		I _I (OD)		(Note 2)	3.6	_	-450	μΑ
3-state output OFF state current		l _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		2.7 to 3.6	_	±10.0	μΑ
Quiescent supply curre	ent	Icc	V _{IN} = V _{CC} or GND		2.7 to 3.6	_	20.0	μА
Increase in I _{CC} per inp	out	Δlcc	V _{IH} = V _{CC} - 0.6 V		2.7 to 3.6		750	μА

Note 1: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch from HIGH-to-LOW.



DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteristi	cs	Symbol	Test C	ondition	V _{CC} (V)	Min	Max	Unit
languat usalta sis	H-level	V _{IH}	-		2.3 to 2.7	1.6	_	V
Input voltage	L-level	V _{IL}	-	_	2.3 to 2.7	_	0.7	V
				I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	_	
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -6 mA	2.3	2.0	_	
				I _{OH} = -12 mA	2.3	1.8	_	
Output voltage				I _{OH} = -18 mA	2.3	1.7	_	V
		V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \mu A$	2.3 to 2.7	_	0.2	
	L-level			I _{OL} = 12 mA	2.3	_	0.4	
				I _{OL} = 18 mA	2.3	_	0.6	
Input leakage current (OEAB, OEBA), SAB, CBA)	SBA, CAB,	I _{IN}	V _{IN} = 0 to 3.6 V		2.3 to 2.7	_	±5.0	μА
Bushold input minimun	n drive hold		V _{IN} = 0.7 V		2.3	45	_	
current		I (HOLD)	V _{IN} = 1.6 V		2.3	-45	_	μА
Bushold input over-driv	Bushold input over-drive current to			(Note 1)	2.7	_	300	^
change state		I _{I (OD)}	(Note 2)		2.7	_	-300	μΑ
3-state output OFF sta	te current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		2.3 to 2.7	_	±10.0	μА
Quiescent supply curre	ent	Icc	$V_{IN} = V_{CC}$ or GND		2.3 to 2.7	_	20.0	μΑ

Note 1: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch from HIGH-to-LOW.



DC Characteristics (Ta = -40 to 85°C, 1.8 V \leq V_{CC} < 2.3 V)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	V _{IH}	-	_		0.7 × V _{CC}	_	V
input voltage	L-level	V _{IL}	_	_	1.8 to 2.3		0.2 × V _{CC}	V
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.8	V _{CC} - 0.2		
Output voltage				$I_{OH} = -6 \text{ mA}$	1.8	1.4	_	V
	L-level	V/	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \mu A$	1.8	_	0.2	
	L-ievei	V _{OL}		I _{OL} = 6 mA	1.8	_	0.3	
Input leakage current (OEAB, OEBA), SAB,	(OEAB, OEBA, SAB, SBA, CAB,		V _{IN} = 0 to 3.6 V		1.8	_	±5.0	μА
Bushold input minimun	n drive hold		V _{IN} = 0.36 V		1.8	25	_	^
current		I (HOLD)	V _{IN} = 1.26 V		1.8	-25	_	μΑ
Bushold input over-driv	Bushold input over-drive current to			(Note 1)	1.8	_	200	
change state		I _I (OD)		(Note 2)	1.8	1.8 — –200 μA		μА
3-state output OFF state current		I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		1.8		±10.0	μΑ
Quiescent supply curre	ent	Icc	V _{IN} = V _{CC} or GND		1.8		20.0	μА

Note 1: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 2: An external driver must sink at least the specified current to switch from HIGH-to-LOW.



AC Characteristics (Ta = –40 to 85°C, input: $t_r = t_f$ = 2.0 ns, C_L = 30 pF, R_L = 500 Ω) (Note 1)

Characteristics	Symbol	Test Condition	1	Min	Max	Unit
	-,		V _{CC} (V)			
			1.8	100	_	
Maximum clock frequency	f _{max}	Figure 1, Figure 3	2.5 ± 0.2	200	_	MHz
			3.3 ± 0.3	250	_	
Propagation delay time			1.8	1.5	7.0	
(An, Bn-Bn, An)	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	0.8	3.5	ns
(All, Bli-Bli, All)	фнг		3.3 ± 0.3	0.6	2.9	
Dranagation dalay time	4		1.8	1.5	8.8	
Propagation delay time (CAB, CBA-Bn, An)	t _{pLH}	Figure 1, Figure 3	2.5 ± 0.2	8.0	4.4	ns
(OAB, OBA-BII, AII)	tpHL		3.3 ± 0.3	0.6	3.2	
Propagation delay time	4		1.8	1.5	8.8	
(SAB, SBA-Bn, An)	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	8.0	4.4	ns
(SAB, SBA-BII, AII)	tpHL		3.3 ± 0.3	0.6	3.5	
Outrout analysis	t _{pZL}	Figure 1, Figure 4, Figure 5	1.8	1.5	9.8	
Output enable time (OEAB, OEBA -An, Bn)			2.5 ± 0.2	8.0	4.9	ns
(OEAB, OEBA-AII, BII)			3.3 ± 0.3	0.6	3.8	
Output dipable time		Figure 1, Figure 4, Figure 5	1.8	1.5	8.1	ns
Output disable time (OEAB, OEBA -An, Bn)	t _{pLZ}		2.5 ± 0.2	8.0	4.5	
(OLAB, OLBA -AII, BII)	t _{pHZ}		3.3 ± 0.3	0.6	3.9	
			1.8	4.0	_	
Minimum pulse width	tw (H)	Figure 1, Figure 3	2.5 ± 0.2	1.5	_	ns
	t _{w (L)}		3.3 ± 0.3	1.5	_	
			1.8	2.5	_	
Minimum setup time	ts	Figure 1, Figure 3	2.5 ± 0.2	1.5	_	ns
			3.3 ± 0.3	1.5	_	
			1.8	1.0	_	
Minimum hold time	t _h	Figure 1, Figure 3	2.5 ± 0.2	1.0	_	ns
			3.3 ± 0.3	1.0	_	
			1.8	_	0.5	
Output to output skew	tosLH	(Note 2)	2.5 ± 0.2	_	0.5	ns
	tosHL		3.3 ± 0.3	_	0.5	

Note 1: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design. $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, \ t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$



Dynamic Switching Characteristics

(Ta = 25°C, input: $t_r = t_f = 2.0 \text{ ns}, C_L = 30 \text{ pF}, R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition			Тур.	Unit
	Í			V _{CC} (V)	,,	
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (N	ote)	1.8	0.25	
Quiet output maximum dynamic V _{OL}	V _{OLP}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (N	ote)	2.5	0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (N	ote)	3.3	8.0	
	V _{OLV}	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (N	ote)	1.8	-0.25	
Quiet output minimum dynamic V _{OI}		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (N	ote)	2.5	-0.6	٧
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (N	ote)	3.3	-0.8	
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (N	ote)	1.8	1.5	
Quiet output minimum dynamic V _{OH}	V _{OHV}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (N	ote)	2.5	1.9	V
, on		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (N	ote)	3.3	2.2	

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

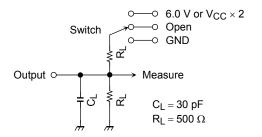
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	(OEAB, OEBA, CAB, CBA, SAB, SBA)	1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C _{I/O}	An, Bn	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$ (Note)	1.8, 2.5, 3.3	20	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$

AC Test Circuit



Parameter	Switch			
t _{pLH} , t _{pHL}	Open			
t _{pLZ} , t _{pZL}	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$			
t _{pHZ} , t _{pZH}	GND			

Figure 1

AC Waveform

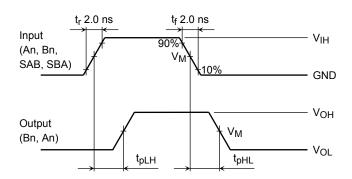


Figure 2 t_{pLH} , t_{pHL}

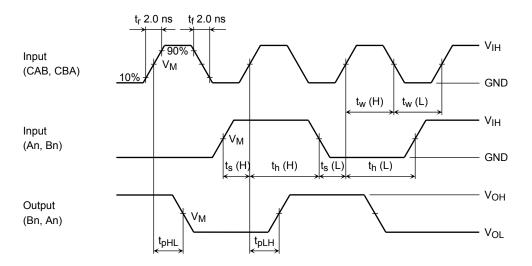


Figure 3 $t_{pLH}, t_{pHL}, t_w, t_s, t_h$

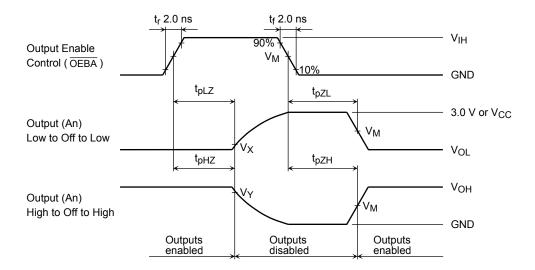


Figure 4 $t_{\text{pLZ}},\,t_{\text{pHZ}},\,t_{\text{pZL}},\,t_{\text{pZH}}$

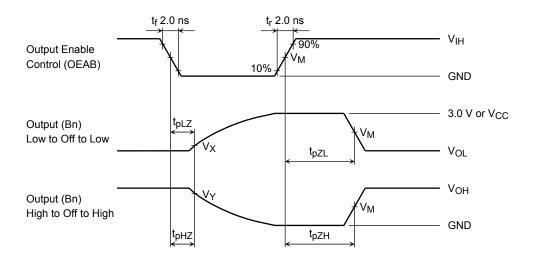


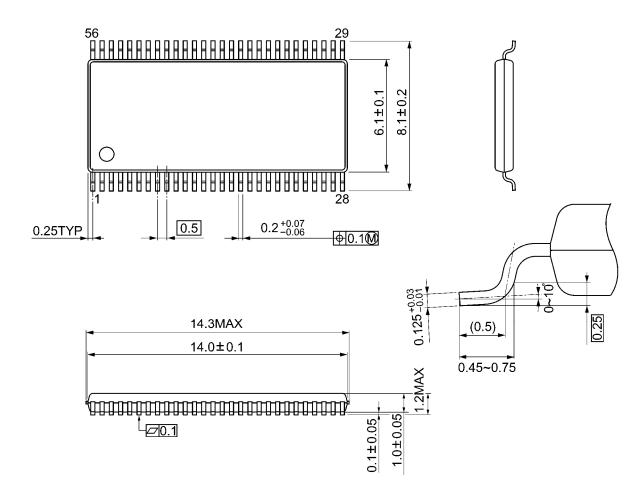
Figure 5 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Symbol		V _{CC}	
Symbol	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2\textrm{V}$	1.8 V
V_{IH}	2.7 V	V _{CC}	V _{CC}
V_{M}	1.5 V	V _{CC} /2	V _{CC} /2
VX	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V
V_{Y}	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V

13 2007-10-19

Package Dimensions

TSSOP56-P-0061-0.50A Unit: mm



Weight: 0.25 g (typ.)

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20070701-EN GENERAL

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